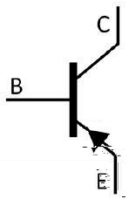


SOT-23 塑封封装 PNP 半导体三极管。Silicon PNP transistor in a SOT-23 Plastic Package.

低电流，低电压，符合 AEC-Q101 标准高可靠性要求，无卤产品。
Low current, Low voltage, Qualified to AEC-Q101 Standards for High Reliability, HF Product.

用于一般放大，满足汽车应用的严格要求。
General power amplifier application, Meet the stringent requirements of automotive applications.



PIN1 : Base PIN 2 : Emitter PIN 3 : Collector

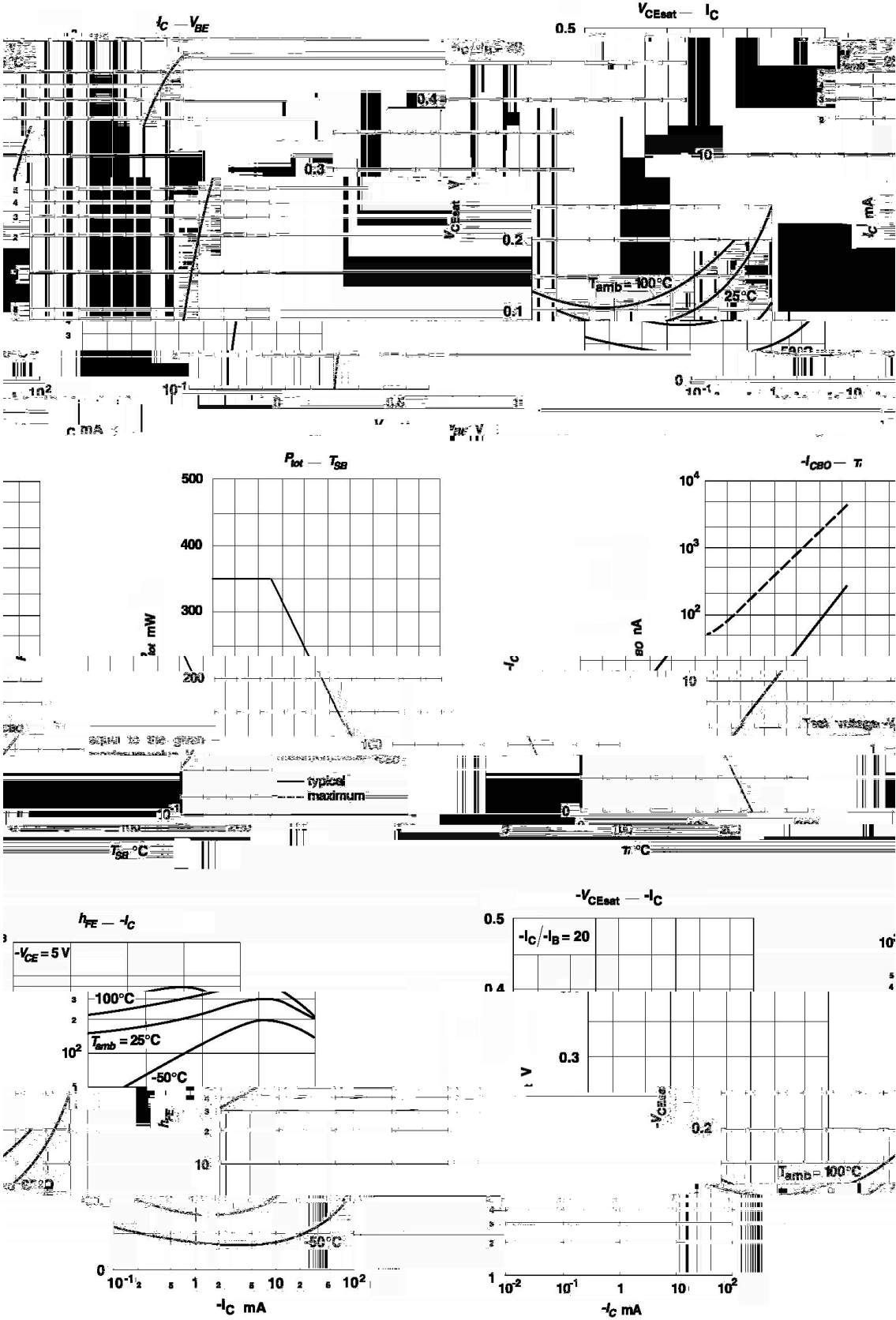
h_{FE} Classifications Symbol	A	B	C
h_{FE} Range	125~250	220~475	420~800
Marking	Q3E	Q3F	Q3G

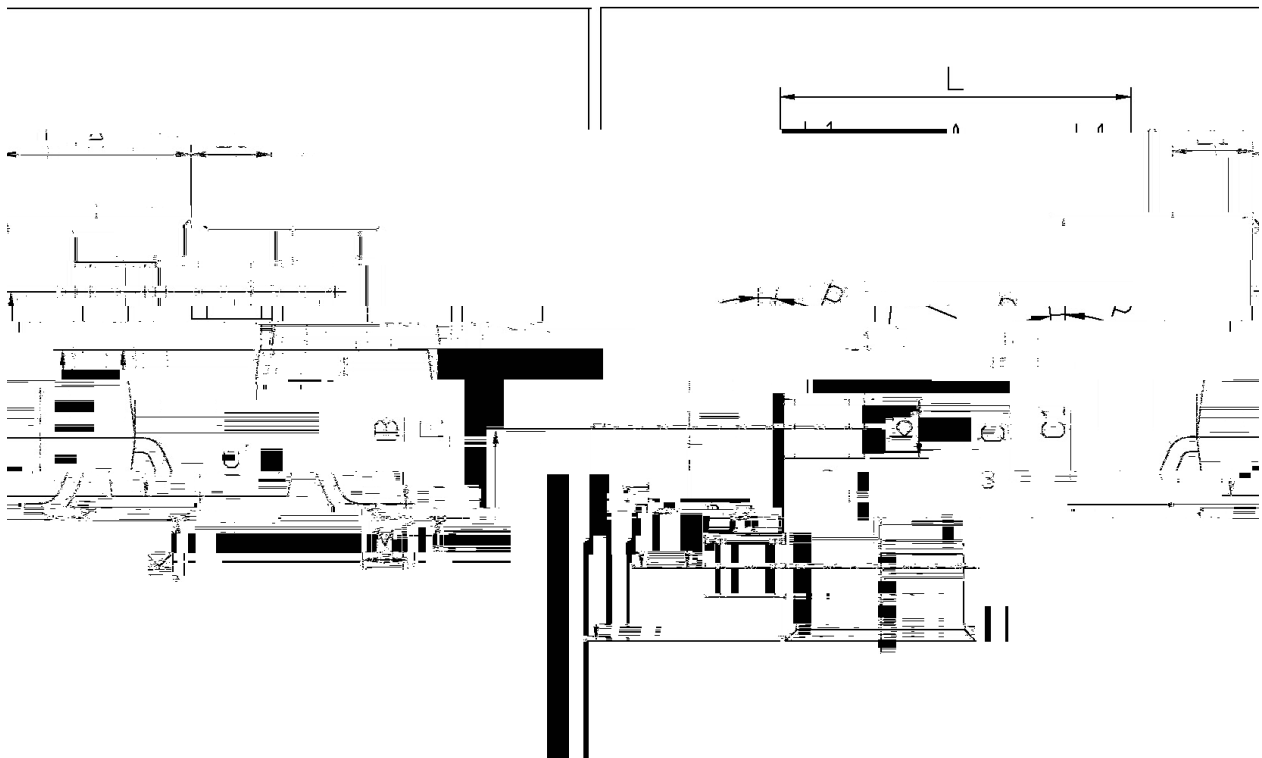
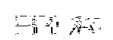
S Q P X E I X X X X X T P 3 2 2

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-50	V
Collector to Emitter Voltage	V_{CEO}	-45	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-100	mA
Collector Power Dissipation	P_C	350	mW
Junction Temperature	T_j	150	°C
Storage Temperature Range	T_{stg}	-55~150	°C

S T X X X X X P 3 2 2

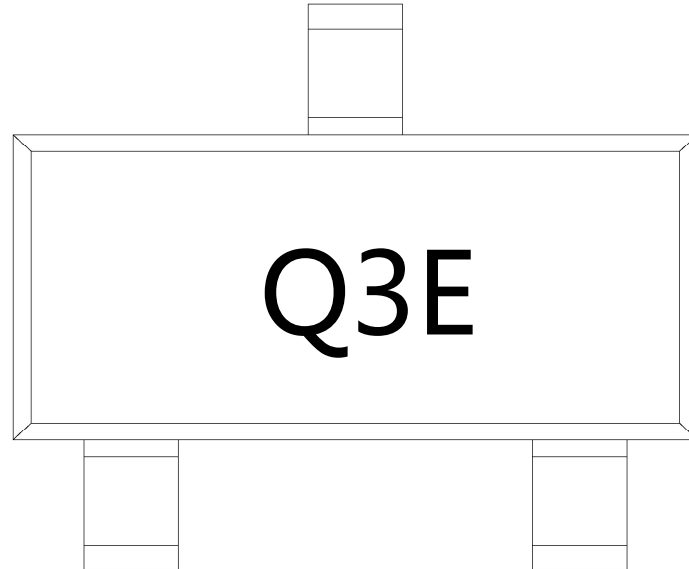
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cut-Off Current	I_{CBO}	$V_{CB}=-30V$ $I_E=0$			-0.015	μA
DC Current Gain	h_{FE}	$V_{CE}=-5.0V$ $I_C=-2.0mA$	125		800	
Collector to Emitter Saturation Voltage	$V_{CE(sat)(1)}$	$I_C=-10mA$ $I_B=-0.5mA$		-0.09	-0.3	V
	$V_{CE(sat)(2)}$	$I_C=-100mA$ $I_B=-5.0mA$		-0.25	-0.65	V
Base to Emitter Saturation Voltage	$V_{BE(sat)(1)}$	$I_C=-10mA$ $I_B=-0.5mA$		-0.7		V
	$V_{BE(sat)(2)}$	$I_C=-100mA$ $I_B=-5.0mA$		-0.9		V
Collector to Emitter Voltage	$V_{CE(ON)(1)}$	$V_{CE}=5.0V$ $I_C=2.0mA$	-0.6	-0.65	-0.75	V
	$V_{CE(ON)(2)}$	$V_{CE}=5.0V$ $I_C=10mA$			-0.82	V
Transition Frequency	f_T	$V_{CE}=5.0V$ $f=100MHz$ $I_C=10mA$		150		MHz
Collector Output Capacitance	C_{ob}	$V_{CB}=10V$ $f=1.0MHz$ $I_E=0$		4.5		pF
Noise Figure	NF	$V_{CE}=6.0V$ $I_C=0.1mA$ $R_g=10K\Omega$ $f=1.0KHz$		2.0	10	dB





Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
	2.2	2.7	C	1.30	1.30Max
E	0.45	0.65	C1	0.90	1.20
A	115	150	c	0.05	0.20
B	2.70	3.10	K	0.10	0.10

S I X I X X X X



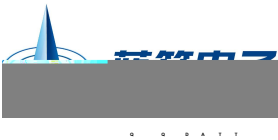
Q

3E

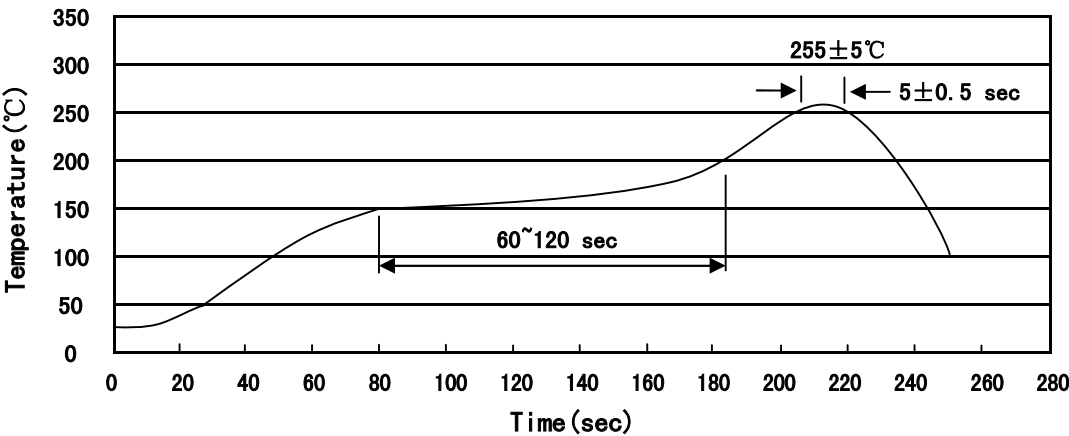
Note:

Q: Automobile halogen-free product Code

3E: Product Type Code



Temperature Profile for IR Reflow Soldering(Pb-Free)



Note:

- 1

150 200

60 120sec;

1.Preheating:150~200°C, Time:60~120sec.
- 2

255±5

5±0.5sec;

2.Peak Temp.:255±5°C, Duration:5±0.5sec.
- 3

2 10°C/sec.

3. Cooling Speed: 2~10°C/sec.

260±5°C

10±1 sec.

Temp.:260±5°C

Time:10±1 sec

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
SOT-23	3,000	10	30,000	6	180000	7" ×8	180×120×180	390×385×205